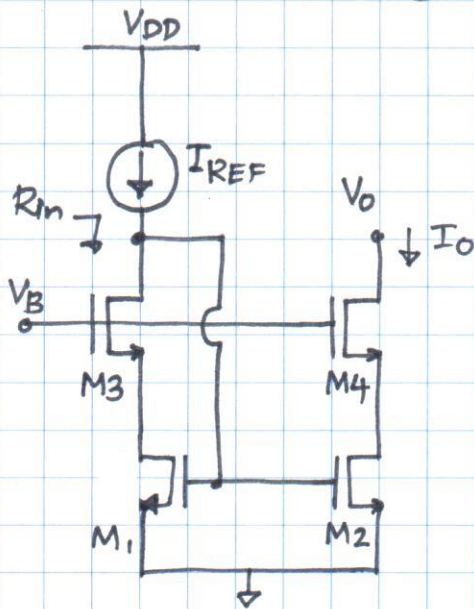


17MAR2020

High Swing Cascode Current Mirror



Keeping all devices in saturation

$$R_{in} \approx \frac{1}{g_{m1}} \quad (\text{PROVE with Small sig. analy.})$$

$$R_{out} = (g_{m4} r_{o4}) \cdot r_{o2}$$

DC balance ✓

$$V_{DS1} = V_{DS2} = V_{dsat}$$

$$V_B = V_{GS3} + V_{dsat}$$

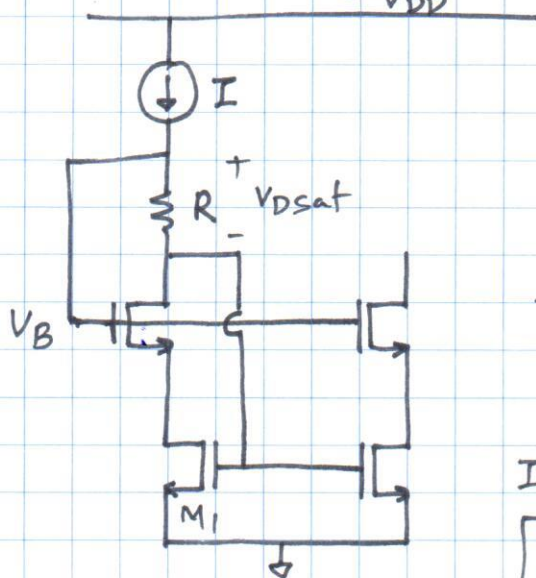
$$= V_T + V_{dsat} + V_{dsat}$$

$$= V_T + 2V_{dsat}$$

$$V_{omin} = V_{dsat4} + V_{dsat2} = 2V_{dsat}$$

⊙ Need to generate V_B .

Smart Biasing



V_B generated using I_{REF} .

$$V_B = (V_T + 2V_{dsat})$$

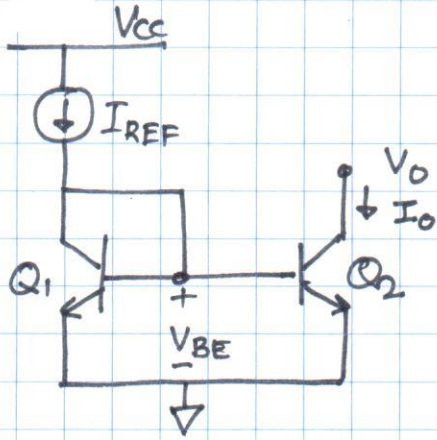
$$I R = V_B - V_{GS1}$$

$$= (V_T + 2V_{dsat}) - (V_T + V_{dsat})$$

$$I R = V_{dsat}$$

$$\boxed{R = \frac{V_{dsat}}{I}}$$

Bipolar Current Mirrors

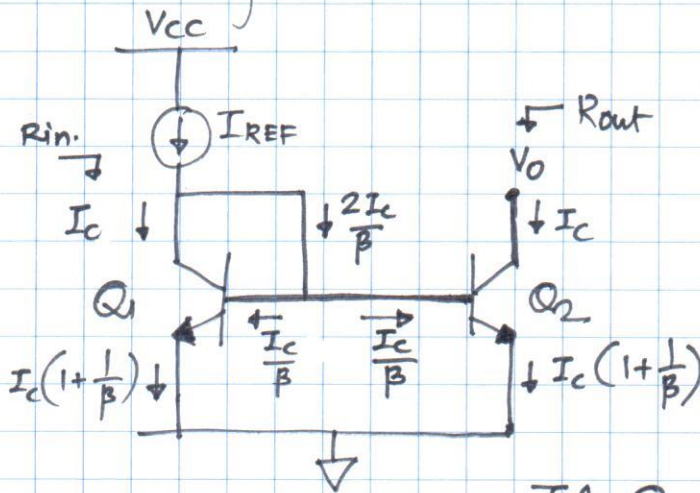


$$V_O > V_{CEsat_2} \quad (0.3V)$$

$$\frac{I_O}{I_{REF}} = \frac{I_{S2}}{I_{S1}} = \frac{\text{Area of EBJ of } Q_2}{\text{Area of EBJ of } Q_1}$$

(Ignoring Base current)
 $\beta = \infty$

Effect of finite transistor β .



$$I_{REF} = I_C + \frac{2I_C}{\beta} = I_C \left(1 + \frac{2}{\beta}\right)$$

$$\frac{I_C}{I_{REF}} = \frac{1}{1 + \frac{2}{\beta}}$$

If Q_2 area is m times bigger

then

$$\frac{I_O}{I_{REF}} = \frac{I_C}{I_{REF}} = \frac{m}{1 + \frac{m+1}{\beta}}$$

$$R_{in} = \frac{1}{g_{m1}}$$

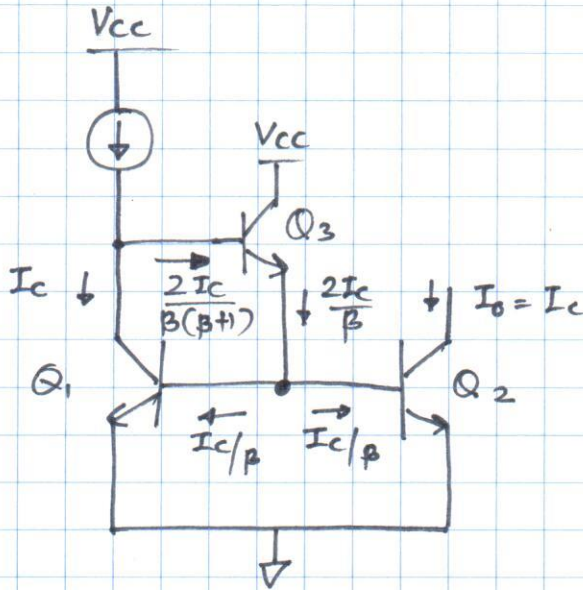
$$R_{out} = r_{o2} = \frac{V_A}{I_O}$$

Taking into account effect of finite r_{o2} (Early Effect)

$$\frac{I_O}{I_{REF}} = \frac{m}{1 + \frac{m+1}{\beta}} \cdot \left(1 + \frac{V_O - V_{BE}}{V_A}\right)$$

= 1 When $V_O = V_{BE}$

Base Current Compensation



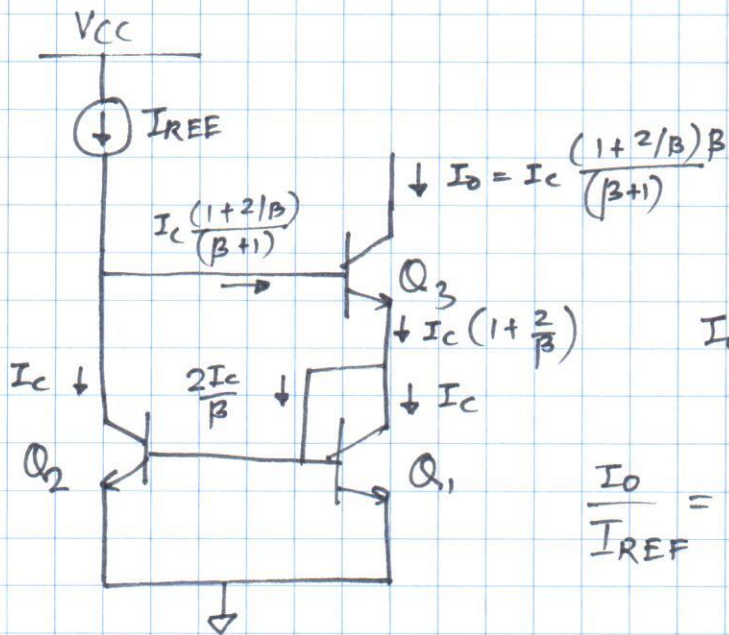
$$I_{REF} = I_C + \frac{2I_C}{\beta(\beta+1)}$$

$$= I_C \left(1 + \frac{2}{\beta(\beta+1)} \right)$$

$$= I_O \left(1 + \frac{2}{\beta(\beta+1)} \right)$$

$$\frac{I_O}{I_{REF}} \approx \frac{1}{1 + \frac{2}{\beta^2}}$$

Wilson Current Mirror



$$I_{REF} = I_C \left[1 + \frac{(1 + 2/\beta)}{(\beta + 1)} \right]$$

$$I_O = I_C \frac{(1 + 2/\beta)\beta}{(\beta + 1)}$$

$$\frac{I_O}{I_{REF}} = \frac{(1 + 2/\beta)\beta}{(\beta + 1)} \cdot \frac{(\beta + 1)}{(\beta + 1 + 1 + 2/\beta)}$$

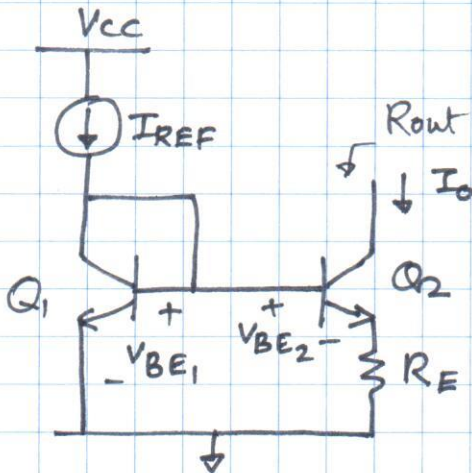
$$= \frac{\beta + 2}{\beta + 2 + 2/\beta} \approx \frac{1}{1 + 2/\beta^2}$$

* $R_{out} = \frac{\beta r_{o3}}{2}$
Cascode effect.

[Reference. - Sedra & Smith pp. 505]

The Widlar Current Source

(Bob Widlar)



$$V_{BE1} = V_T \ln \left(\frac{I_{REF}}{I_S} \right)$$

$$V_{BE2} = V_T \ln \left(\frac{I_O}{I_S} \right)$$

$$V_{BE1} - V_{BE2} = V_T \ln \left(\frac{I_{REF}}{I_O} \right)$$

$$I_O R_E = V_T \ln \left(\frac{I_{REF}}{I_O} \right)$$

* Allows generation of small current using relatively small resistors.

→ "ln" effect $\ln(100) = 4.6$; $\ln(1000) = \underline{\underline{6.9}}$

For example: to generate $10 \mu\text{A}$ from 5V .

$$R = \frac{5\text{V} - 0.7\text{V}}{10 \mu\text{A}} = 430 \text{ k}\Omega \quad (\text{large area})$$

Using $I_{REF} = 1\text{mA}$; we can generate $I_O = 10 \mu\text{A}$

$$10 \mu\text{A} \times R_E = 26\text{mV} \cdot \ln \left(\frac{1\text{mA}}{10 \mu\text{A}} \right)$$

$$R_E = \frac{26\text{mV}}{10 \mu\text{A}} \times 4.6 = 11.96 \text{ k}\Omega$$

Advantage

$$R_{out} = \left[1 + g_m (R_E \parallel r_{\pi}) \right] r_o \quad \underline{\underline{\text{high}}}$$